



Features

- Adopt FRD chip
- Low forward Voltage drop
- Fast reverse recovery time
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

Typical Applications

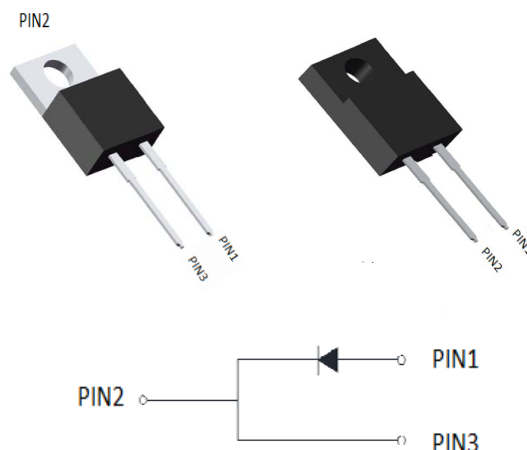
Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

Mechanical Data

- **Package:** TO-220AC ITO-220AC
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked

Maximum Ratings (Ta=25°C Unless otherwise specified)

TYPE	V _{RSM} V	V _{RRM} V
MUR3060	600	600
MUR3060F	600	600



Symbol	Test Conditions	Maximum Ratings	Unit	
I _{FRMS}	T _{VJ} =T _{VJM}	60	A	
I _{FAVM}	T _C =85°C; rectangular, d=0.5	30		
I _{FRM}	t _p <10us; rep. rating, pulse width limited by T _{VJM}	375		
I _{FSM}	T _{VJ} =45°C	t=10ms (50Hz), sine t=8.3ms (60Hz), sine	300 320	A
	T _{VJ} =150°C	t=10ms(50Hz), sine t=8.3ms(60Hz), sine	260 280	
I ² t	T _{VJ} =45°C	t=10ms (50Hz), sine t=8.3ms (60Hz), sine	450 420	A ² s
	T _{VJ} =150°C	t=10ms(50Hz), sine t=8.3ms(60Hz), sine	340 320	
T _{VJ}		-40...+150	°C	
T _{VJM}		150		
T _{stg}		-40...+150		
P _{tot}	T _C =25°C	125	W	
M _d	Mounting torque	0.8...1.2	Nm	
Weight	typical	6	g	



Characteristics (Typical)

Symbol	Test Conditions	Characteristic Values		Unit
		typ.	max.	
I_R	$T_{VJ}=25^{\circ}\text{C}; V_R=V_{RRM}$		100	μA
	$T_{VJ}=25^{\circ}\text{C}; V_R=0.8 \cdot V_{RRM}$		50	μA
	$T_{VJ}=125^{\circ}\text{C}; V_R=0.8 \cdot V_{RRM}$		7	mA
V_F	$I_F=30\text{A}; T_{VJ}=150^{\circ}\text{C}$ $T_{VJ}=25^{\circ}\text{C}$		1.5 1.7	V
V_{To}	For power-loss calculations only		1.01	V
r_T	$T_{VJ}=T_{VJM}$		7.1	$\text{m}\Omega$
R_{thJC} R_{thCK} R_{thJA}		0.25	1 35	K/W
t_{rr}	$I_F=1\text{A}; -di_F/dt=100\text{A}/\mu\text{s}; V_R=30\text{V}; T_{VJ}=25^{\circ}\text{C}$	40	55	ns
I_{RM}	$V_R=350\text{V}; I_F=30\text{A}; -di_F/dt=240\text{A}/\mu\text{s}; L<0.05\mu\text{H}; T_{VJ}=100^{\circ}\text{C}$	10	11	A

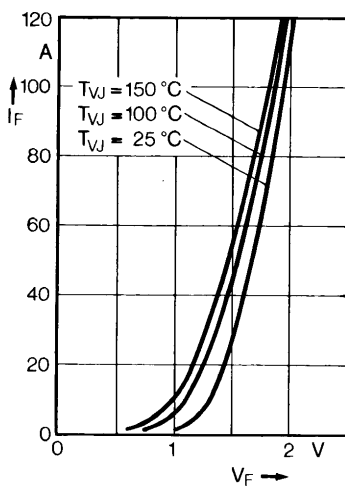


Fig. 1 Forward current versus voltage drop.

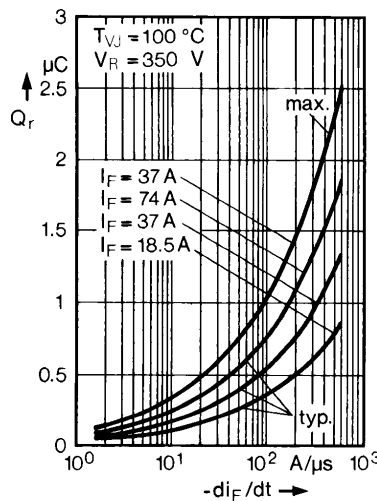


Fig. 2 Recovery charge versus $-di_F/dt$.

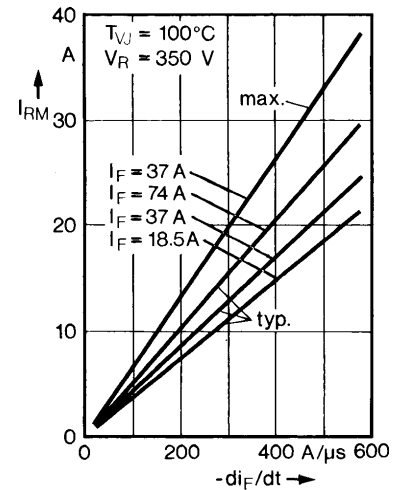


Fig. 3 Peak reverse current versus $-di_F/dt$.

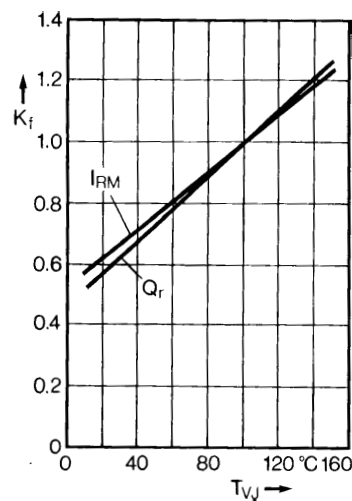


Fig. 4 Dynamic parameters versus junction temperature.

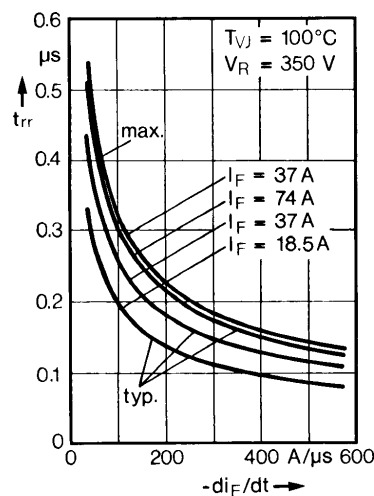


Fig. 5 Recovery time versus $-di_F/dt$.

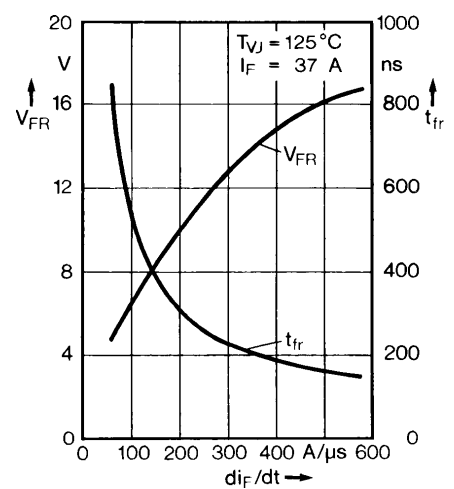
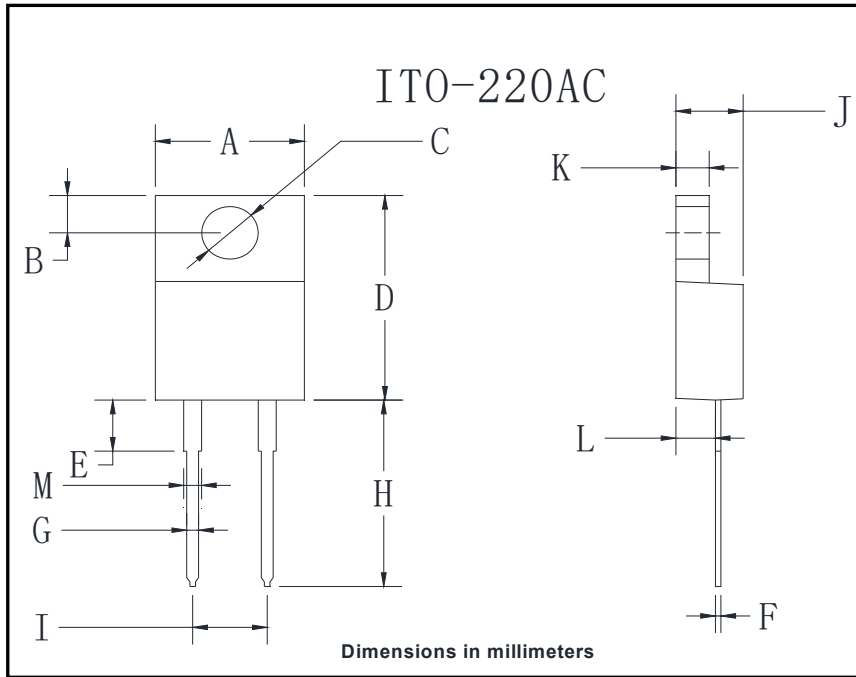
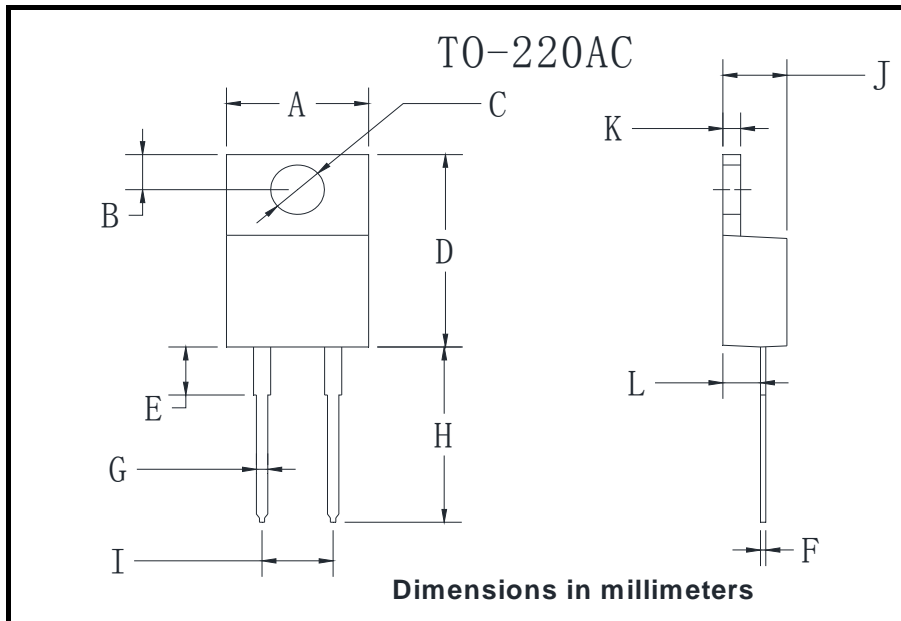


Fig. 6 Peak forward voltage versus di_F/dt .

Outline Dimensions



ITO-220AC		
Dim	Min	Max
A	9.8	10.2
B	2.25	2.75
C	2.95	3.45
D	14.75	15.25
E	3.5	4.1
F	0.45	0.75
G	0.45	0.75
H	13.35	14.15
I	4.97	5.23
J	4.3	4.8
K	2.5	2.74
L	2.58	2.82
M	1.03	1.43



TO-220AC		
Dim	Min	Max
A	9.95	10.35
B	2.55	2.95
C	3.75	4.05
D	14.95	15.25
E	3.75	4.25
F	0.26	0.5
G	0.68	0.94
H	13.3	13.9
I	4.86	5.26
J	4.38	4.78
K	1.14	1.4
L	2.37	2.79